

RoHS

COMPLIANT HALOGEN

FREE Available

Vishay Siliconix

N-Channel 250-V (D-S) MOSFET

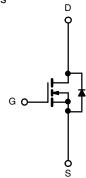
PRODUCT SUMMARY				
V _{DS} (V)	Rr_{DS(on)} (Ω)	I _D (A)		
250	0.155 at V _{GS} = 10 V	3.0		
	0.162 at V _{GS} = 6.0 V	2.9		

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- PWM-Optimized TrenchFET[®] Power MOSFET
- 100 % R_g Tested
- Avalanche Tested

APPLICATIONS

- Primary Side Switch In:
 - Telecom Power Supplies
 - Distributed Power Architectures
 - Miniature Power Modules



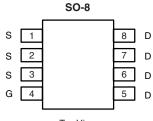
N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	250		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current /T 150 °C)	T _A = 25 °C	– I _D	3.0	2.1	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		2.4	1.7	
Pulsed Drain Current		I _{DM}	30		А
Continuous Source Current (Diode Conduction) ^a		I _S	2.6	1.3	
Avalanche Current	L = 0.1 mH	I _{AS}	13		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS} 8.4		8.4 m	
	T _A = 25 °C	P _D	3.1	1.56	W
Maximum Power Dissipation ^a	T _A = 70 °C	ГD	2.0	1.0	vv
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lumation to Ambienta	t ≤ 10 s	R _{thJA}	33	40	°C/W
Maximum Junction-to-Ambient ^a	Steady State		65	80	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	17	21	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



Top View

Ordering Information: Si4434DY-T1-E3 (Lead (Pb)-free) Si4434DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static				_	-			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2.0		4.0	V		
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			± 100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 250 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1			
		V_{DS} = 250 V, V_{GS} = 0 V, T_{J} = 55 °C			15	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10$ V, $V_{GS} = 10$ V	20			А		
	R _{DS(on)}	V _{GS} = 10 V, I _D = 3.0 A		0.129	0.155	0		
Drain-Source On-State Resistance ^a		$V_{GS} = 6.0 \text{ V}, \text{ I}_{D} = 2.9 \text{ A}$		0.131	0.162	Ω		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 3.0 \text{ A}$		14		S		
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = 2.8 A, $V_{\rm GS}$ = 0 V		0.75	1.2	V		
Dynamic ^b			•		•			
Total Gate Charge	Qg			34	50	nC		
Gate-Source Charge	Q _{gs}	V_{DS} = 100 V, V_{GS} = 10 V, I_{D} = 3.0 A		6.8				
Gate-Drain Charge	Q _{gd}			10.5		1		
Gate Resistance	R _g		0.6	1.2	1.8	Ω		
Turn-On Delay Time	t _{d(on)}			16	25			
Rise Time	t _r	V_{DD} = 100 V, R_L = 25 Ω		23	35	ns		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_{\text{D}}\cong$ 4.0 A, V_{GEN} = 10 V, R_{g} = 6 Ω		47	70			
Fall Time	t _f			19	30			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.8 A, dI/dt = 100 A/μs		100	150			

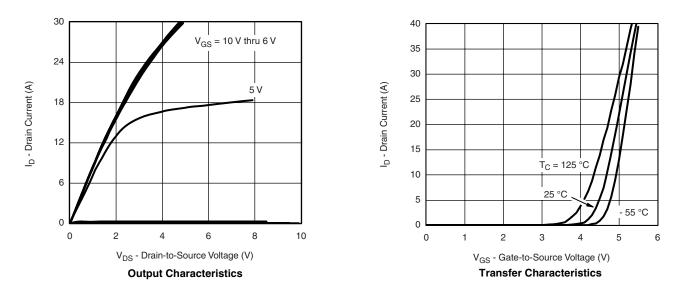
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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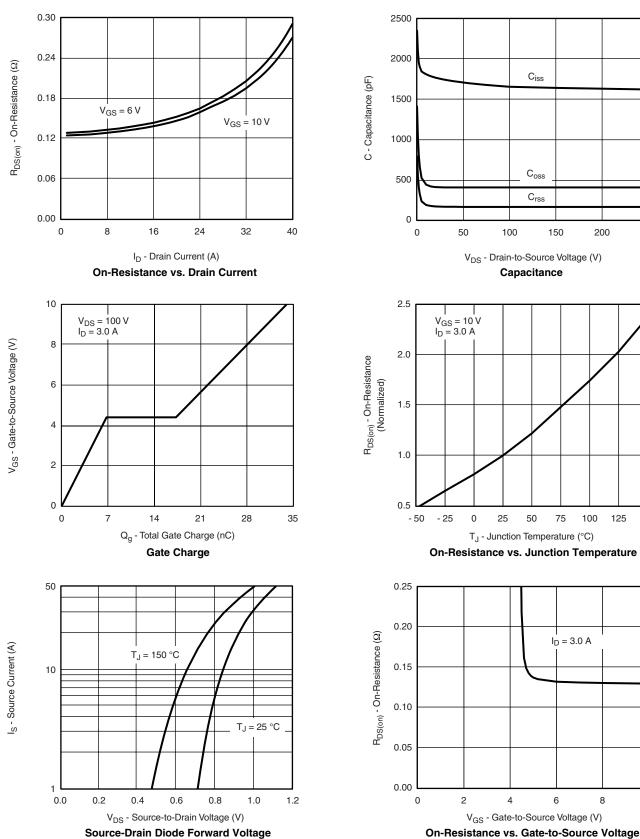
Si4434DY Vishay Siliconix

250

150

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

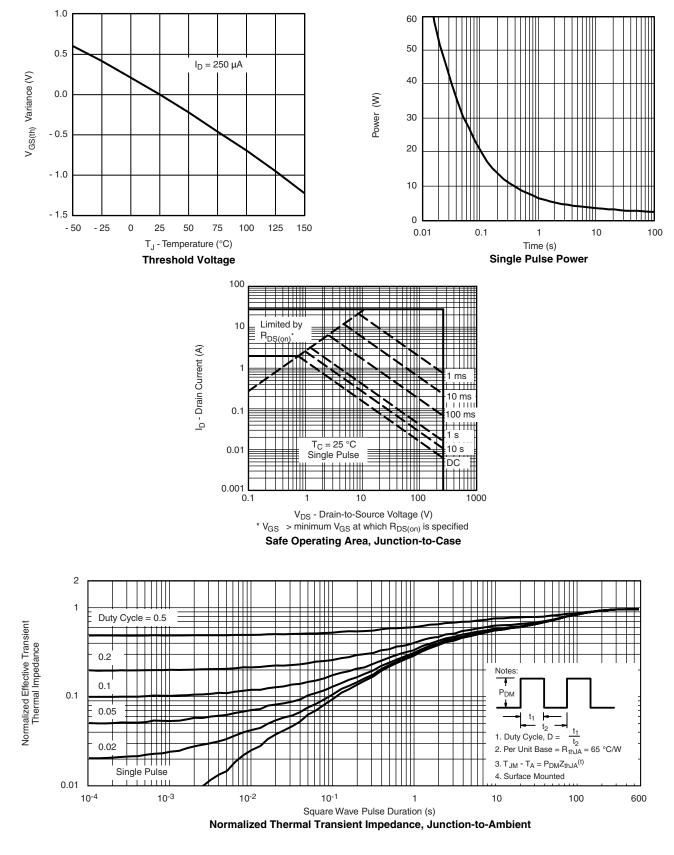
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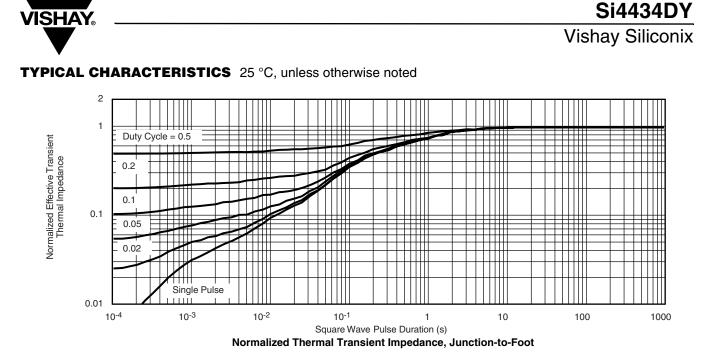
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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72562.



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